E·XFL



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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	80MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	3.3V
Operating Temperature	0°C ~ 95°C (TA)
Security Features	-
Package / Case	256-BBGA
Supplier Device Package	256-PBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc850dezq80bu

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Overview

The CPM of the MPC850 supports up to seven serial channels, as follows:

- One or two serial communications controllers (SCCs). The SCCs support Ethernet, ATM (MPC850SR and MPC850DSL), HDLC and a number of other protocols, along with a transparent mode of operation.
- One USB channel
- Two serial management controllers (SMCs)
- One I²C port
- One serial peripheral interface (SPI).

Table 1 shows the functionality supported by the members of the MPC850 family.

Part	Number of SCCs Supported	Ethernet Support	ATM Support	USB Support	Multi-channel HDLC Support	Number of PCMCIA Slots Supported
MPC850	1	Yes	-	Yes	-	1
MPC850DE	2	Yes	-	Yes	-	1
MPC850SR	2	Yes	Yes	Yes	Yes	1
MPC850DSL	2	Yes	Yes	Yes	No	1

Table 1. MPC850 Functionality Matrix

Additional documentation may be provided for parts listed in Table 1.



NP,

2 Features

Figure 1 is a block diagram of the MPC850, showing its major components and the relationships among those components:

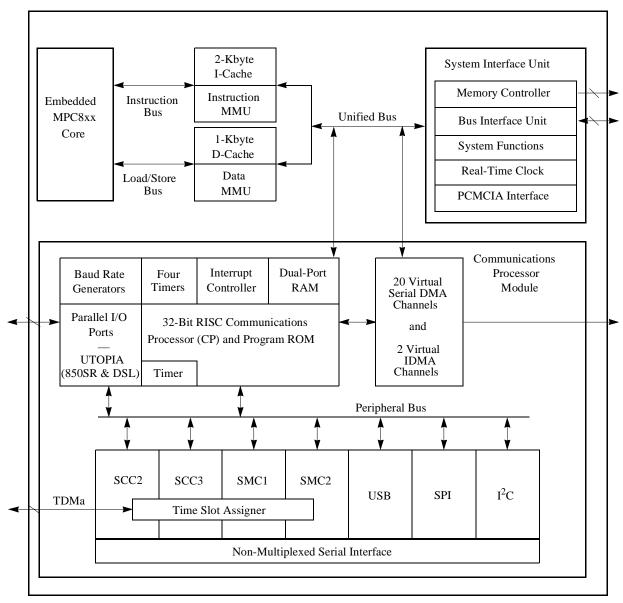
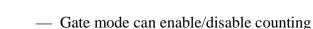


Figure 1. MPC850 Microprocessor Block Diagram

The following list summarizes the main features of the MPC850:

- Embedded single-issue, 32-bit MPC8xx core (implementing the PowerPC architecture) with thirty-two 32-bit general-purpose registers (GPRs)
 - Performs branch folding and branch prediction with conditional prefetch, but without conditional execution





- Interrupt can be masked on reference match and event capture
- Interrupts
 - Eight external interrupt request (IRQ) lines
 - Twelve port pins with interrupt capability
 - Fifteen internal interrupt sources
 - Programmable priority among SCCs and USB
 - Programmable highest-priority request
- Single socket PCMCIA-ATA interface
 - Master (socket) interface, release 2.1 compliant
 - Single PCMCIA socket
 - Supports eight memory or I/O windows
- Communications processor module (CPM)
 - 32-bit, Harvard architecture, scalar RISC communications processor (CP)
 - Protocol-specific command sets (for example, GRACEFUL STOP TRANSMIT stops transmission after the current frame is finished or immediately if no frame is being sent and CLOSE RXBD closes the receive buffer descriptor)
 - Supports continuous mode transmission and reception on all serial channels
 - Up to 8 Kbytes of dual-port RAM
 - Twenty serial DMA (SDMA) channels for the serial controllers, including eight for the four USB endpoints
 - Three parallel I/O registers with open-drain capability
- Four independent baud-rate generators (BRGs)
 - Can be connected to any SCC, SMC, or USB
 - Allow changes during operation
 - Autobaud support option
- Two SCCs (serial communications controllers)
 - Ethernet/IEEE 802.3, supporting full 10-Mbps operation
 - HDLC/SDLCTM (all channels supported at 2 Mbps)
 - HDLC bus (implements an HDLC-based local area network (LAN))
 - Asynchronous HDLC to support PPP (point-to-point protocol)
 - AppleTalk[®]
 - Universal asynchronous receiver transmitter (UART)
 - Synchronous UART
 - Serial infrared (IrDA)
 - Totally transparent (bit streams)
 - Totally transparent (frame based with optional cyclic redundancy check (CRC))



Characteristic	Symbol	Min	Мах	Unit
Input low voltage	VIL	GND	0.8	V
EXTAL, EXTCLK input high voltage	VIHC	0.7*(VCC)	VCC+0.3	V
Input leakage current, Vin = 5.5 V (Except TMS, $\overline{\text{TRST}}$, DSCK and DSDI pins)	l _{in}	—	100	μA
Input leakage current, Vin = $3.6V$ (Except TMS, TRST, DSCK and DSDI pins)	l _{in}	—	10	μA
Input leakage current, Vin = 0V (Except TMS, $\overline{\text{TRST}}$, DSCK and DSDI pins)	l _{in}	—	10	μA
Input capacitance	C _{in}	—	20	pF
Output high voltage, IOH = -2.0 mA, VDDH = 3.0V except XTAL, XFC, and open-drain pins	VOH	2.4	_	V
Output low voltage CLKOUT ³ IOL = 3.2 mA^{1} IOL = 5.3 mA^{2} IOL = $7.0 \text{ mA} \text{ PA}[14]/\overline{\text{USBOE}}, \text{ PA}[12]/\text{TXD2}$ IOL = $8.9 \text{ mA} \overline{\text{TS}}, \overline{\text{TA}}, \overline{\text{TEA}}, \overline{\text{BI}}, \overline{\text{BB}}, \overline{\text{HRESET}}, \overline{\text{SRESET}}$	VOL	_	0.5	V

Table 5. DC Electrical Specifications (continued)

 A[6:31], TSIZ0/REG, TSIZ1, D[0:31], DP[0:3]/IRQ[3:6], RD/WR, BURST, RSV/IRQ2, IP_B[0:1]/IWP[0:1]/VFLS[0:1], IP_B2/IOIS16_B/AT2, IP_B3/IWP2/VF2, IP_B4/LWP0/VF0, IP_B5/LWP1/VF1, IP_B6/DSDI/AT0, IP_B7/PTR/AT3, PA[15]/USBRXD, PA[13]/RXD2, PA[9]/L1TXDA/SMRXD2, PA[8]/L1RXDA/SMTXD2, PA[7]/CLK1/TIN1/L1RCLKA/BRGO1, PA[6]/CLK2/TOUT1/TIN3, PA[5]/CLK3/TIN2/L1TCLKA/BRGO2, PA[4]/CLK4/TOUT2/TIN4, PB[31]/SPISEL, PB[30]/SPICLK/TXD3, PB[29]/SPIMOSI /RXD3, PB[28]/SPIMISO/BRGO3, PB[27]/I2CSDA/BRGO1, PB[26]/I2CSCL/BRGO2, PB[25]/SMTXD1/TXD3, PB[24]/SMRXD1/RXD3, PB[23]/SMSYN1/SDACK1, PB[22]/SMSYN2/SDACK2, PB[19]/L1ST1, PB[18]/RTS2/L1ST2, PB[17]/L1ST3, PB[16]/L1RQa/L1ST4, PC[15]/DREQ0/L1ST5, PC[14]/DREQ1/RTS2/L1ST6, PC[13]/L1ST7/RTS3, PC[12]/L1RQa/L1ST8, PC[11]/USBRXP, PC[10]/TGATE1/USBRXN, PC[9]/CTS2, PC[8]/CD2/TGATE1, PC[7]/USBTXP, PC[6]/USBTXN, PC[5]/CTS3/L1TSYNCA/SDACK1, PC[4]/CD3/L1RSYNCA, PD[15], PD[14], PD[13], PD[12], PD[11], PD[10], PD[9], PD[8], PD[7], PD[6], PD[5], PD[4], PD[3]

- ² BDIP/GPL_B5, BR, BG, FRZ/IRQ6, CS[0:5], CS6/CE1_B, CS7/CE2_B, WE0/BS_AB0/IORD, WE1/BS_AB1/IOWR, WE2/BS_AB2/PCOE, WE3/BS_AB3/PCWE, GPL_A0/GPL_B0, OE/GPL_A1/GPL_B1, GPL_A[2:3]/GPL_B[2:3]/CS[2:3], UPWAITA/GPL_A4/AS, UPWAITB/GPL_B4, GPL_A5, ALE_B/DSCK/AT1, OP2/MODCK1/STS, OP3/MODCK2/DSDO
- 3 The MPC850 IBIS model must be used to accurately model the behavior of the Clkout output driver for the full and half drive setting. Due to the nature of the Clkout output buffer, IOH and IOL for Clkout should be extracted from the IBIS model at any output voltage level.

5 **Power Considerations**

The average chip-junction temperature, T_J, in °C can be obtained from the equation:

$$T_{J} = T_{A} + (P_{D} \bullet \theta_{JA})(1)$$

where

 $T_{A} =$ Ambient temperature, °C



 θ_{IA} = Package thermal resistance, junction to ambient, °C/W

 $\begin{aligned} \mathbf{P}_{\mathrm{D}} &= \mathbf{P}_{\mathrm{INT}} + \mathbf{P}_{\mathrm{I/O}} \\ \mathbf{P}_{\mathrm{INT}} &= \mathbf{I}_{\mathrm{DD}} \ge \mathbf{V}_{\mathrm{DD}}, \text{watts}\text{---chip internal power} \end{aligned}$

 $P_{I/O}$ = Power dissipation on input and output pins—user determined

For most applications $P_{I/O} < 0.3 \bullet P_{INT}$ and can be neglected. If $P_{I/O}$ is neglected, an approximate relationship between P_D and T_I is:

 $P_{\rm D} = K \div (T_{\rm I} + 273^{\circ} \rm C)(2)$

Solving equations (1) and (2) for K gives:

 $\mathbf{K} = \mathbf{P}_{\mathrm{D}} \bullet (\mathbf{T}_{\mathrm{A}} + 273^{\circ}\mathrm{C}) + \mathbf{\theta}_{\mathrm{JA}} \bullet \mathbf{P}_{\mathrm{D}}^{2}(3)$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and T_J can be obtained by solving equations (1) and (2) iteratively for any value of T_A .

5.1 Layout Practices

Each V_{CC} pin on the MPC850 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{CC} power supply should be bypassed to ground using at least four 0.1 µF by-pass capacitors located as close as possible to the four sides of the package. The capacitor leads and associated printed circuit traces connecting to chip V_{CC} and GND should be kept to less than half an inch per capacitor lead. A four-layer board is recommended, employing two inner layers as V_{CC} and GND planes.

All output pins on the MPC850 have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data busses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{CC} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins.

6 Bus Signal Timing

Table 6 provides the bus operation timing for the MPC850 at 50 MHz, 66 MHz, and 80 MHz. Timing information for other bus speeds can be interpolated by equation using the MPC850 Electrical Specifications Spreadsheet found at http://www.mot.com/netcomm.

The maximum bus speed supported by the MPC850 is 50 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC850 used at 66 MHz must be configured for a 33 MHz bus).

The timing for the MPC850 bus shown assumes a 50-pF load. This timing can be derated by 1 ns per 10 pF. Derating calculations can also be performed using the MPC850 Electrical Specifications Spreadsheet.



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Num	Characteristic	50 MHz 66 MHz			80	MHz	FFACT	Cap Load (default	Unit	
-		Min	Max	Min	Max	Min	Max	_	50 pF)	
B28c	CLKOUT falling edge to WE[0–3] negated GPCM write access TRLX = 0,1 CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	7.00	14.00	11.00	18.00	9.00	16.00	0.375	50.00	ns
B28d	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0,1 CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	_	14.00	_	18.00		16.00	0.375	50.00	ns
B29	$\overline{WE[0-3]}$ negated to D[0-31], DP[0-3] high-Z GPCM write access, CSNT = 0	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B29a	WE[0–3] negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 0 CSNT = 1, EBDF = 0	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B29b	CS negated to D[0–31], DP[0–3], high-Z GPCM write access, ACS = 00, TRLX = 0 & CSNT = 0	3.00		6.00		4.00		0.250	50.00	ns
B29c	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	8.00		13.00		11.00		0.500	50.00	ns
B29d	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 0	28.00		43.00		36.00		1.500	50.00	ns
B29e	CS negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	28.00		43.00		36.00		1.500	50.00	ns
B29f	WE[0–3] negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, EBDF = 1	5.00		9.00		7.00		0.375	50.00	ns
B29g	CS negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	5.00		9.00		7.00		0.375	50.00	ns

Table 6.	Bus Operation	Timing ¹	(continued)
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		50 MHz 66 MHz				00.5	/LI-		Cap Load	
Num	Characteristic					80 MHz		FFACT	(default	Unit
		Min	Max	Min	Мах	Min	Мах		50 pF)	
B29h	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access TRLX = 0, CSNT = 1, EBDF = 1	25.00		39.00		31.00		1.375	50.00	ns
B29i	$\overline{\text{CS}}$ negated to D[0–31], DP[0–3] high-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	25.00	_	39.00	_	31.00	_	1.375	50.00	ns
B30	CS, WE[0–3] negated to A[6–31] invalid GPCM write access ⁹	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B30a	$\label{eq:weighted} \hline \hline WE[0-3] \mbox{ negated to } A[6-31] \mbox{ invalid } \\ GPCM \mbox{ write access, } TRLX = 0, \\ CSNT = 1, \end{cases} \mbox{ CSNT = 1, } \hline CS \mbox{ negated to } \\ A[6-31] \mbox{ invalid GPCM write } \\ access \mbox{ TRLX = 0, } CSNT = 1, \\ ACS = 10 \mbox{ or } ACS = 11, \mbox{ EBDF = } \\ 0 \\ \hline \hline \end{array}$	8.00		13.00		11.00		0.500	50.00	ns
B30b	$\label{eq:WE0-3} \hline \hline WE[0-3] \mbox{ negated to } A[6-31] \mbox{ invalid } \\ GPCM \mbox{ write access, } TRLX = 1, \\ CSNT = 1. \hline CS \mbox{ negated to } \\ A[6-31] \mbox{ Invalid GPCM write } \\ access \mbox{ TRLX = 1, } CSNT = 1, \\ ACS = 10 \mbox{ or } ACS = 11, \mbox{ EBDF = } \\ 0 \\ \hline \end{array}$	28.00	_	43.00	_	36.00	_	1.500	50.00	ns
B30c	$\label{eq:WE[0-3]} \begin{array}{l} \mbox{megated to A[6-31]} \\ \mbox{invalid} \\ \mbox{GPCM write access, TRLX = 0,} \\ \mbox{CSNT = 1. } \hline CS \mbox{ negated to} \\ \mbox{A[6-31] invalid GPCM write} \\ \mbox{access, TRLX = 0, CSNT = 1,} \\ \mbox{ACS = 10 or ACS = 11, EBDF =} \\ \mbox{1} \end{array}$	5.00	_	8.00	_	6.00		0.375	50.00	ns
B30d	$\label{eq:WE[0-3]} \begin{array}{l} \hline WE[0-3] \mbox{ negated to } A[6-31] \\ \hline \mbox{ invalid GPCM write access} \\ \hline TRLX = 1, \mbox{ CSNT = 1}, \mbox{ CS} \\ \hline \mbox{ negated to } A[6-31] \mbox{ invalid} \\ \hline \mbox{ GPCM write access } TRLX = 1, \\ \hline \mbox{ CSNT = 1}, \mbox{ ACS = 10 or } ACS = \\ \hline \mbox{ 11, EBDF = 1} \end{array}$	25.00		39.00		31.00		1.375	50.00	ns



Num	Characteristic	50 MHz 66 M			MHz	Hz 80 MHz			Cap Load (default	Unit
		Min	Max	Min	Max	Min	Мах	_	50 pF)	•
B33a	CLKOUT rising edge to GPL valid - as requested by control bit GxT3 in the corresponding word in the UPM	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B34	A[6–31] and D[0–31] to CS valid - as requested by control bit CST4 in the corresponding word in the UPM	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B34a	A[6–31] and D[0–31] to \overline{CS} valid - as requested by control bit CST1 in the corresponding word in the UPM	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B34b	A[6–31] and D[0–31] to CS valid - as requested by CST2 in the corresponding word in UPM	13.00	—	21.00	—	17.00	—	0.750	50.00	ns
B35	A[6-31] to \overline{CS} valid - as requested by control bit BST4 in the corresponding word in UPM	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B35a	A[6–31] and D[0–31] to BS valid - as requested by BST1 in the corresponding word in the UPM	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B35b	A[6–31] and D[0–31] to BS valid - as requested by control bit BST2 in the corresponding word in the UPM	13.00	_	21.00	_	17.00	_	0.750	50.00	ns
B36	A[6–31] and D[0–31] to GPL valid - as requested by control bit GxT4 in the corresponding word in the UPM	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B37	UPWAIT valid to CLKOUT falling edge 10	6.00	—	6.00	—	6.00	—	—	50.00	ns
B38	CLKOUT falling edge to UPWAIT valid ¹⁰	1.00	—	1.00	—	1.00	—	—	50.00	ns
B39	AS valid to CLKOUT rising edge	7.00	_	7.00	_	7.00	_	—	50.00	ns
B40	A[6–31], TSIZ[0–1], RD/WR, BURST, valid to CLKOUT rising edge.	7.00		7.00		7.00		—	50.00	ns
B41	TS valid to CLKOUT rising edge (setup time)	7.00	_	7.00	—	7.00	—	_	50.00	ns



Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default	Unit
	Unaracteristic	Min	Max	Min	Max	Min	Max		50 pF)	Unit
B42	CLKOUT rising edge to \overline{TS} valid (hold time)	2.00	_	2.00	_	2.00	_	—	50.00	ns
B43	AS negation to memory controller signals negation	_	TBD	_	TBD	TBD	_	—	50.00	ns

 Table 6. Bus Operation Timing ¹ (continued)

The minima provided assume a 0 pF load, whereas maxima assume a 50pF load. For frequencies not marked on the part, new bus timing must be calculated for all frequency-dependent AC parameters. Frequency-dependent AC parameters are those with an entry in the FFactor column. AC parameters without an FFactor entry do not need to be calculated and can be taken directly from the frequency column corresponding to the frequency marked on the part. The following equations should be used in these calculations.

For a frequency F, the following equations should be applied to each one of the above parameters: For minima:

$$D = \frac{FFACTOR \times 1000}{F} + (D_{50} - 20 \times FFACTOR)$$

For maxima:

$$D = \frac{FFACTOR \times 1000}{F} + \frac{(D_{50} - 20 \times FFACTOR)}{F} + \frac{1ns(CAP \text{ LOAD} - 50) / 10}{F}$$

where:

D is the parameter value to the frequency required in ns

F is the operation frequency in MHz

D₅₀ is the parameter value defined for 50 MHz

CAP LOAD is the capacitance load on the signal in question.

FFACTOR is the one defined for each of the parameters in the table.

- ² Phase and frequency jitter performance results are valid only if the input jitter is less than the prescribed value.
- ³ If the rate of change of the frequency of EXTAL is slow (i.e. it does not jump between the minimum and maximum values in one cycle) or the frequency of the jitter is fast (i.e., it does not stay at an extreme value for a long time) then the maximum allowed jitter on EXTAL can be up to 2%.
- ⁴ The timing for BR output is relevant when the MPC850 is selected to work with external bus arbiter. The timing for BG output is relevant when the MPC850 is selected to work with internal bus arbiter.
- ⁵ The setup times required for TA, TEA, and BI are relevant only when they are supplied by an external device (and not when the memory controller or the PCMCIA interface drives them).
- ⁶ The timing required for BR input is relevant when the MPC850 is selected to work with the internal bus arbiter. The timing for BG input is relevant when the MPC850 is selected to work with the external bus arbiter.
- ⁷ The D[0–31] and DP[0–3] input timings B20 and B21 refer to the rising edge of the CLKOUT in which the TA input signal is asserted.
- ⁸ The D[0:31] and DP[0:3] input timings B20 and B21 refer to the falling edge of CLKOUT. This timing is valid only for read accesses controlled by chip-selects controlled by the UPM in the memory controller, for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.
- ⁹ The timing B30 refers to \overline{CS} when ACS = '00' and to $\overline{WE[0:3]}$ when CSNT = '0'.
- ¹⁰ The signal UPWAIT is considered asynchronous to CLKOUT and synchronized internally. The timings specified in B37 and B38 are specified to enable the freeze of the UPM output signals.
- ¹¹ The $\overline{\text{AS}}$ signal is considered asynchronous to CLKOUT.



Figure 2 is the control timing diagram.

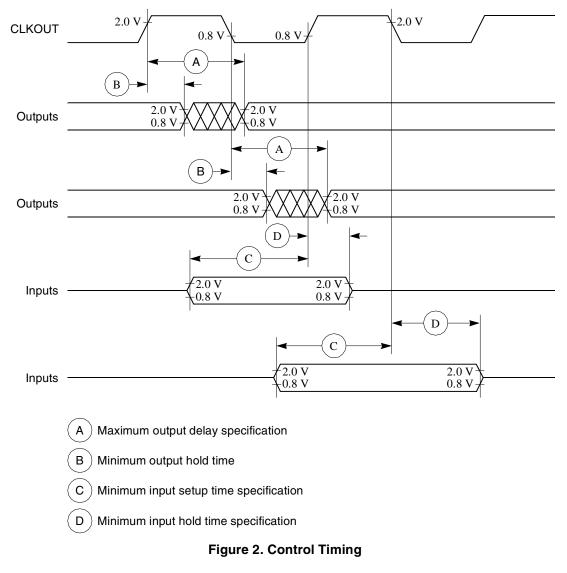


Figure 3 provides the timing for the external clock.

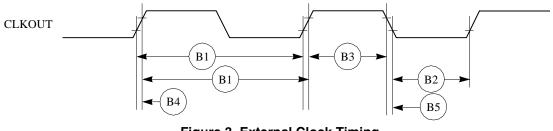


Figure 3. External Clock Timing



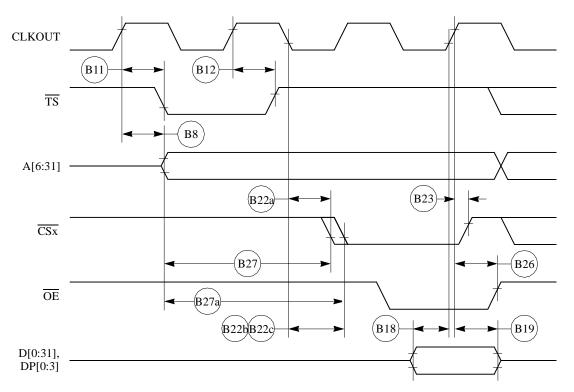


Figure 12. External Bus Read Timing (GPCM Controlled—TRLX = 1, ACS = 10, ACS = 11)



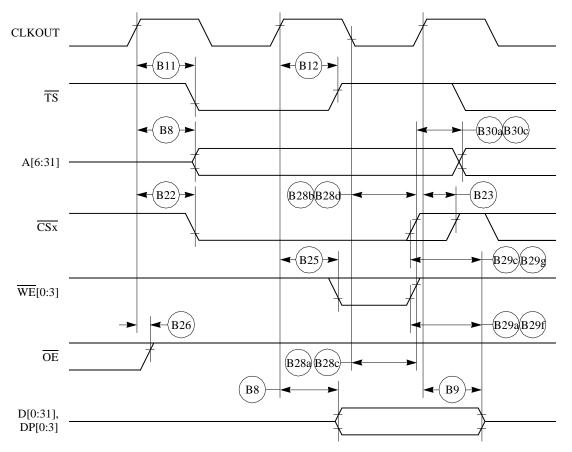


Figure 14. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 1)



Figure 16 provides the timing for the external bus controlled by the UPM.

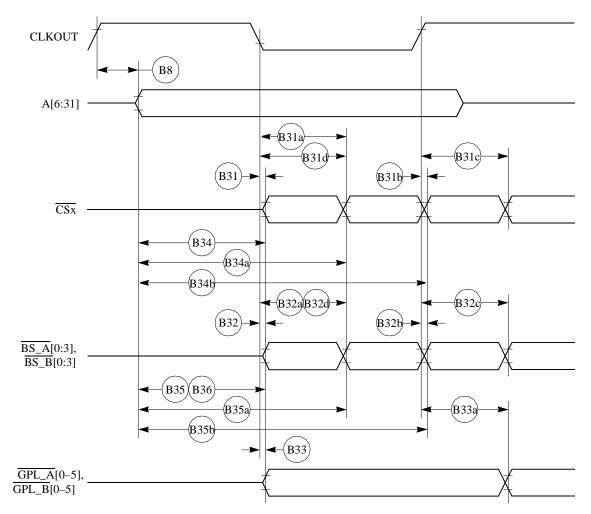


Figure 16. External Bus Timing (UPM Controlled Signals)



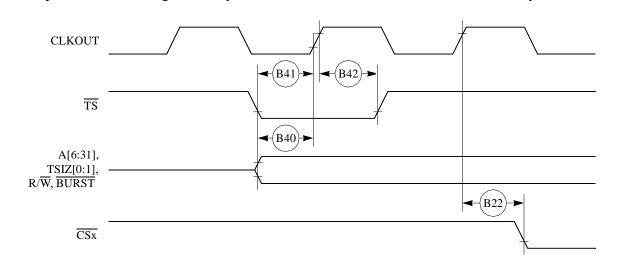
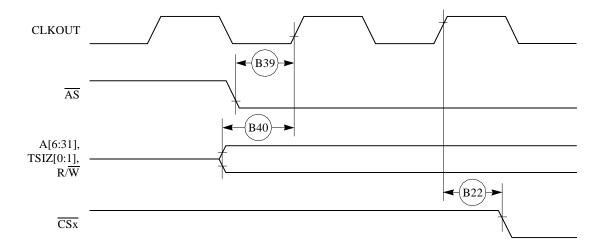


Figure 19 provides the timing for the synchronous external master access controlled by the GPCM.

Figure 19. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 20 provides the timing for the asynchronous external master memory access controlled by the GPCM.



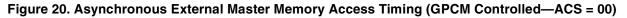


Figure 21 provides the timing for the asynchronous external master control signals negation.

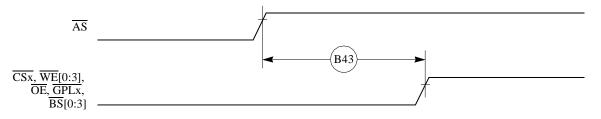


Figure 21. Asynchronous External Master—Control Signals Negation Timing



Figure 31 shows the reset timing for the data bus configuration.

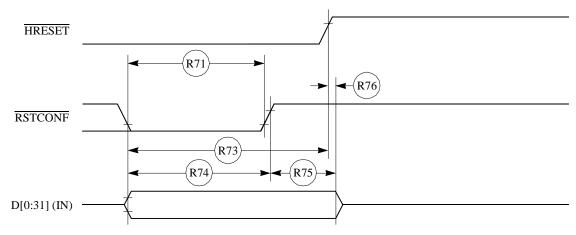


Figure 31. Reset Timing—Configuration from Data Bus

Figure 32 provides the reset timing for the data bus weak drive during configuration.

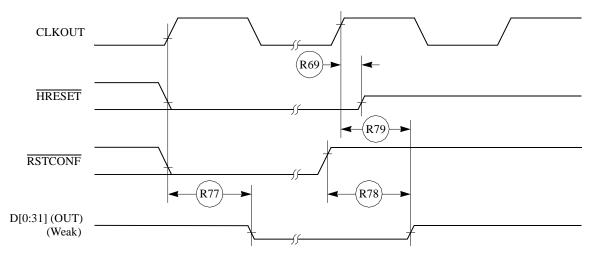


Figure 32. Reset Timing—Data Bus Weak Drive during Configuration



CPM Electrical Characteristics

8.6 SCC in NMSI Mode Electrical Specifications

Table 18 provides the NMSI external clock timing.

Num	Characteristic	All Frequencie	Unit	
Num	onaracteristic	Min	Ont	
100	RCLKx and TCLKx frequency 1 (x = 2, 3 for all specs in this table)	1/SYNCCLK	-	ns
101	RCLKx and TCLKx width low	1/SYNCCLK +5	_	ns
102	RCLKx and TCLKx rise/fall time	_	15.00	ns
103	TXDx active delay (from TCLKx falling edge)	0.00	50.00	ns
104	RTSx active/inactive delay (from TCLKx falling edge)	0.00	50.00	ns
105	CTSx setup time to TCLKx rising edge	5.00		ns
106	RXDx setup time to RCLKx rising edge	5.00	_	ns
107	RXDx hold time from RCLKx rising edge ²	5.00	_	ns
108	CDx setup time to RCLKx rising edge	5.00	_	ns

¹ The ratios SyncCLK/RCLKx and SyncCLK/TCLKx must be greater than or equal to 2.25/1.

² Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signal.

Table 19 provides the NMSI internal clock timing.

Table 19. NMSI Internal Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Мах	onn
100	RCLKx and TCLKx frequency $1 (x = 2, 3 \text{ for all specs in this table})$	0.00	SYNCCLK/3	MHz
102	RCLKx and TCLKx rise/fall time		—	ns
103	TXDx active delay (from TCLKx falling edge)	0.00	30.00	ns
104	RTSx active/inactive delay (from TCLKx falling edge)	0.00	30.00	ns
105	CTSx setup time to TCLKx rising edge	40.00	—	ns
106	RXDx setup time to RCLKx rising edge	40.00	—	ns
107	RXDx hold time from RCLKx rising edge ²	0.00	—	ns
108	CDx setup time to RCLKx rising edge	40.00	—	ns

¹ The ratios SyncCLK/RCLKx and SyncCLK/TCLK1x must be greater or equal to 3/1.

² Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signals.



Num	Characteristic	All Frequencies		Unit
		Min	Max	Unit
134	TENA inactive delay (from TCLKx rising edge)	10.00	50.00	ns
138	CLKOUT low to SDACK asserted ²	_	20.00	ns
139	CLKOUT low to SDACK negated ²	_	20.00	ns

Table 20. Ethernet Timing (continued)

¹ The ratios SyncCLK/RCLKx and SyncCLK/TCLKx must be greater or equal to 2/1.

² SDACK is asserted whenever the SDMA writes the incoming frame destination address into memory.

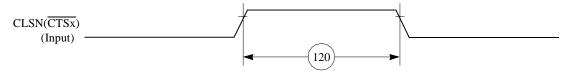


Figure 53. Ethernet Collision Timing Diagram

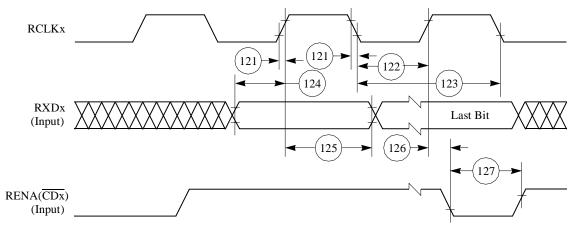


Figure 54. Ethernet Receive Timing Diagram





8.10 SPI Slave AC Electrical Specifications

Table 23 provides the SPI slave timings as shown in Figure 59 and Figure 60.

Table 23. SPI Slave Timing

Num	Characteristic	All Frequ	Unit	
	Characteristic	Min	Max	onn
170	Slave cycle time	2		t _{cyc}
171	Slave enable lead time	15.00	—	ns
172	Slave enable lag time	15.00	—	ns
173	Slave clock (SPICLK) high or low time	1	—	t _{cyc}
174	Slave sequential transfer delay (does not require deselect)	1	—	t _{cyc}
175	Slave data setup time (inputs)	20.00	—	ns
176	Slave data hold time (inputs)	20.00	—	ns
177	Slave access time	_	50.00	ns
178	Slave SPI MISO disable time	_	50.00	ns
179	Slave data valid (after SPICLK edge)	_	50.00	ns
180	Slave data hold time (outputs)	0.00	—	ns
181	Rise time (input)	_	15.00	ns
182	Fall time (input)—15.00		ns	



Document Revision History

10 Document Revision History

Table 28 lists significant changes between revisions of this document.

Table 28. Document Revision History

Revision	Date	Change
2	7/2005	Added footnote 3 to Table 5 (previously Table 4.5) and deleted IOL limit.
1	10/2002	Added MPC850DSL. Corrected Figure 25 on page 34.
0.2	04/2002	Updated power numbers and added Rev. C
0.1	11/2001	Removed reference to 5 Volt tolerance capability on peripheral interface pins. Replaced SI and IDL timing diagrams with better images. Updated to new template, added this revision table.



Document Revision History

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